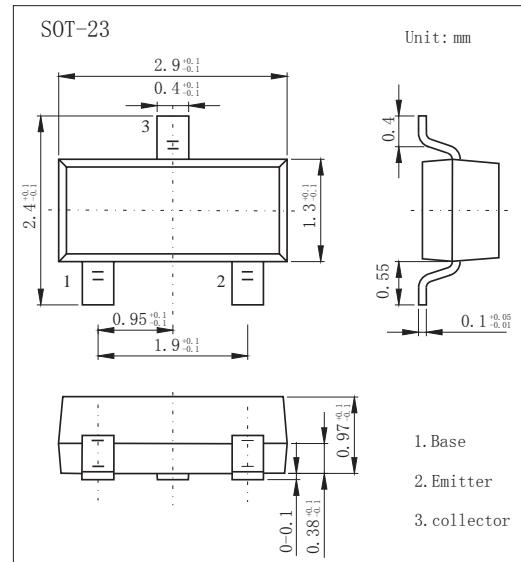


SOT-23 Plastic-Encapsulate Transistors
Features

- Excellent hFE Linearity
- Complementary to KTC3876/KTC3876S
- PNP Transistors

MECHANICAL DATA

- Case style:SOT-23molded plastic
- Mounting position:any


MAXIMUM RATINGS AND CHARACTERISTICS

@ 25°C Ambient Temperature (unless otherwise noted)

Parameter	Symbol	Rating	Unit
Collector - Base Voltage	V _{CBO}	-35	V
Collector - Emitter Voltage	V _{CEO}	-30	
Emitter - Base Voltage	V _{EBO}	-5	
Collector Current - Continuous	I _C	-500	mA
Base Current	I _B	-50	
Collector Power Dissipation T _c = 25°C	P _C	150	mW
Junction Temperature	T _J	150	°C
Storage Temperature range	T _{stg}	-55 to 150	

PACKAGE INFORMATION

Device	Package	Shipping
KTA1505	SOT-23	3000/Tape&Reel

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector- base breakdown voltage	V _{CBO}	I _C = -100 uA, I _E =0	-35			V
Collector- emitter breakdown voltage	V _{CEO}	I _C = -1 mA, I _B =0	-30			
Emitter - base breakdown voltage	V _{EBO}	I _E = -100 uA, I _C =0	-5			
Collector-base cut-off current	I _{CB0}	V _{CB0} = -35V , I _E =0			-0.1	uA
Emitter cut-off current	I _{EBO}	V _{EB0} = -5V , I _C =0			-0.1	
Collector-emitter saturation voltage	V _{CE(sat)}	I _C =-100mA, I _B =-10mA			-0.25	V
Base - emitter saturation voltage	V _{BE(sat)}	I _C =-100mA, I _B =-10mA			-1.2	
Base - emitter voltage	V _{BE}	V _{CE} = -1V, I _C = -100mA			-1	
DC current gain	h _{FE}	V _{CE} = -1V, I _C = -100mA	70		400	
		O V _{CE} = -6V, I _C = -400mA	25			
		Y	40			
Collector output capacitance	C _{ob}	V _{CB0} = -6V, I _E = 0,f=1MHz			13	pF
Transition frequency	f _T	V _{CE} = -6V, I _C = -20mA			200	MHz

Classification of hfe(1)

Type	KTA1505-O	KTA1505-Y	KTA1505-G
Range	70-140	120-240	200-400
Marking	AZO	AZY	AZG

RATINGS AND CHARACTERISTIC CURVES

■ Typical Characteristics

